

Notice of References Cited	Application/Control No. 09/651,790	Applicant(s)/Patent Under Reexamination BALUSWAMY ET AL	
	Examiner Marcos D. Pizarro-Crespo	Art Unit 2814	Page 1 of 1

U.S. PATENT DOCUMENTS

★	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
A	US-5,883,012	03-1999	Chiou et al.	438/748
B	US-			
C	US-			
D	US-			
E	US-			
F	US-			
G	US-			
H	US-			
I	US-			
J	US-			
K	US-			
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M	US-			

FOREIGN PATENT DOCUMENTS

★	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
N					
O					
P					
Q					
R					
S					
T					

NON-PATENT DOCUMENTS

★	Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
U	Ghandhi, VLSI Fabrication Principles Silicon and Gallium Arsenide, 2nd ed., 1994, John Wiley & Sons, Inc., New York, pp.589
V	
W	
X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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